



30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

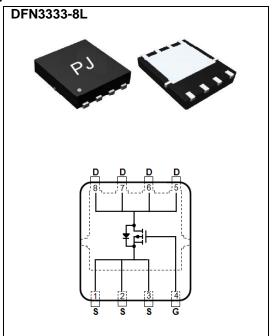
-50 A

Features

- $R_{DS(ON)}$, V_{GS} @-10V, I_D @-10A<8.5m Ω
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-8A<14m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN3333-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.001 ounces, 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	-30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	- I _D	-50	А	
	T _C =100°C		-32		
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	-200		
Power Dissipation	T _C =25°C	Po	60	10/	
	T _C =100°C		24	W	
Continuous Drain Current	T _A =25°C	I _D	-10	А	
	T _A =70°C		-8	А	
Power Dissipation	T _A =25°C		2.0	10/	
Power Dissipation	T _A =70°C	Pb	1.3	W	
Operating Junction and Storage	e Temperature Range	T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	2.1	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-1.0	-1.5	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-10A	-	7.1	8.5	mΩ	
		V _{GS} =-4.5V,I _D =-8A	-	10	14		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-10A, V _{GS} =-4.5V ^(Note 1,2)	-	27	-	nC	
Gate-Source Charge	Q_gs		-	8.4	-		
Gate-Drain Charge	Q_gd	V _{GS} =-4.5 V	-	8.7	-		
Input Capacitance	Ciss	\/ 45\/ \/ O\/	-	3228	-	pF	
Output Capacitance	Coss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	396	-		
Reverse Transfer Capacitance	Crss	I=1.UIVIHZ	-	254	-		
Turn-On Delay Time	td _(on)	\/ 45\/\ID 44	-	10	-	ns	
Turn-On Rise Time	t _r	V _{DS} =-15V,ID=-1A,	-	13	-		
Turn-Off Delay Time	td _(off)	V_{GS} =-10V, R_{G} =6 Ω	-	111	-		
Turn-Off Fall Time	t _f		-	51	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	ı				-50	А	
Diode Forward Current	I _S		-	-	-50	^	
Diode Forward Voltage	V_{SD}	I _S =-1A,V _{GS} =0V	-	-0.7	-1	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

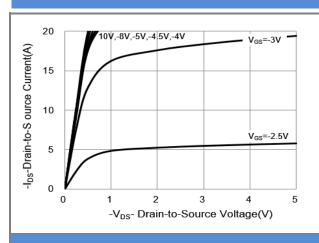


Fig.1 On-Region Characteristics

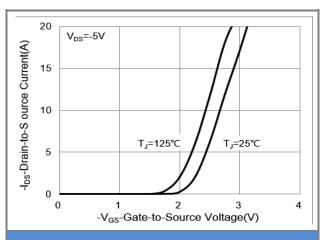


Fig.2 Transfer Characteristics

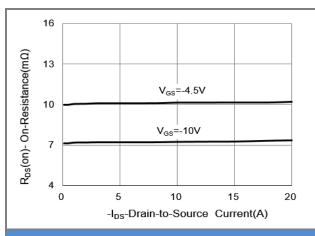


Fig.3 On-Resistance vs. Drain Current

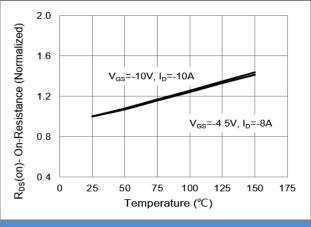


Fig.4 On-Resistance vs. Junction temperature

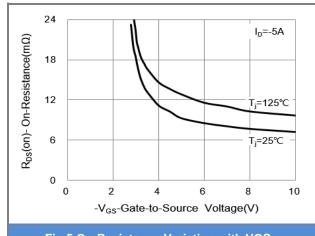


Fig.5 On-Resistance Variation with VGS.

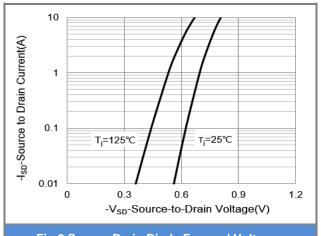


Fig.6 Source-Drain Diode Forward Voltage





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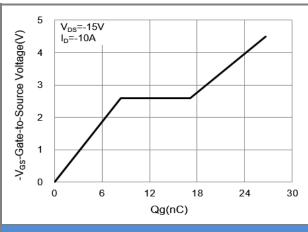


Fig.7 Gate-Charge Characteristics

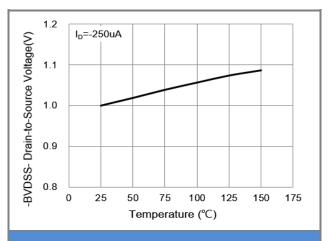


Fig.8 Breakdown Voltage Variation vs. Temperature.

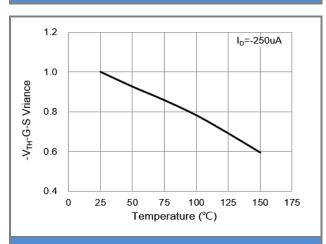


Fig.9 Threshold Voltage Variation with Temperature

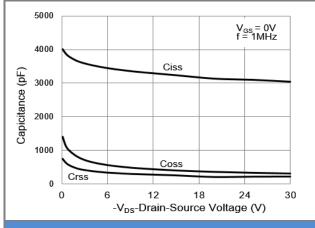
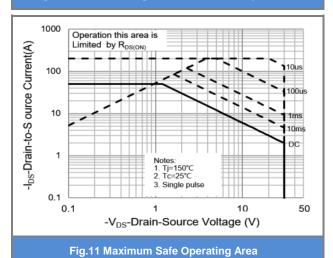


Fig.10 Capacitance vs. Drain-Source Voltage







TYPICAL CHARACTERISTIC CURVES

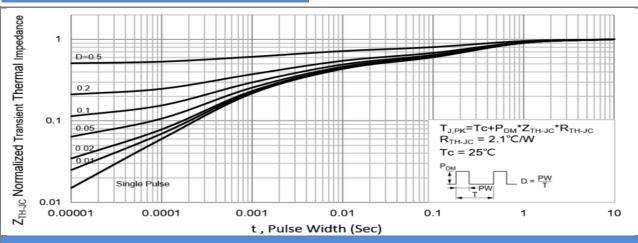


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

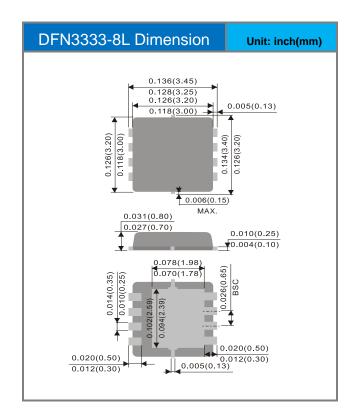


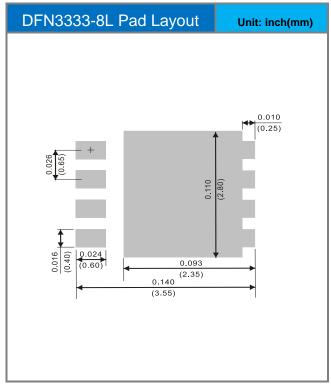


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJQ4401P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4401	Halogen free	

Packaging Information & Mounting Pad Layout









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